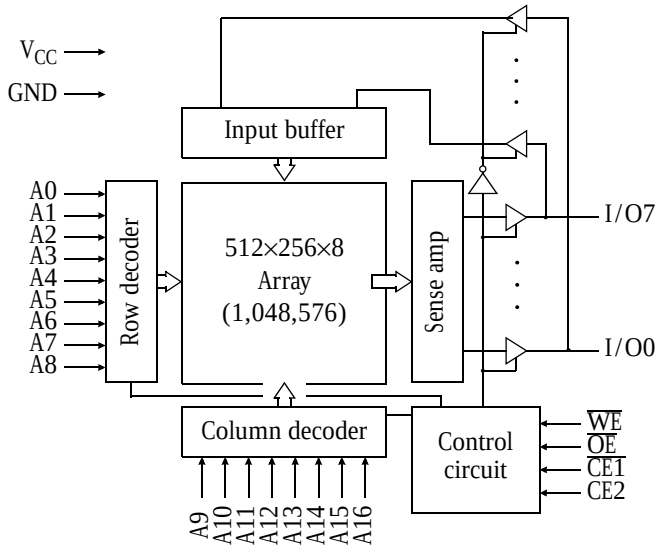
5V/3.3V 128KX8 CMOS SRAM (Evolutionary Pinout)

Features

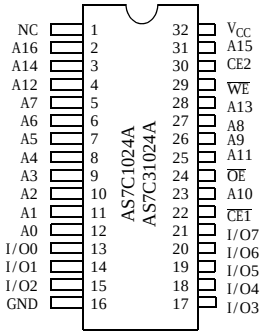
- AS7C1024A (5V version)
- AS7C31024A (3.3V version)
- Industrial and commercial temperatures
- Organization: 131,072 words x 8 bits
- High speed
  - 10/12/15/20 ns address access time
  - 5, 6, 7, 8 ns output enable access time
- Low power consumption: ACTIVE
  - 853 mW (AS7C1024A) / max @ 10 ns
  - 522 mW (AS7C31024A) / max @ 10 ns
- Low power consumption: STANDBY
  - 55 mW (AS7C1024A) / max CMOS
  - 36 mW (AS7C31024A) / max CMOS
- Latest 6T 0.25u CMOS technology
- Easy memory expansion with $\overline{CE1}$, CE2, $\overline{OE}$ inputs
- TTL/LVTTL-compatible, three-state I/O
- 32-pin JEDEC standard packages
  - 300 mil SOJ
  - 400 mil SOJ
  - 8 × 20mm TSOP 1
  - 8 x 13.4mm sTSOP 1
- ESD protection ≥ 2000 volts
- Latch-up current ≥ 200 mA

Logic block diagram

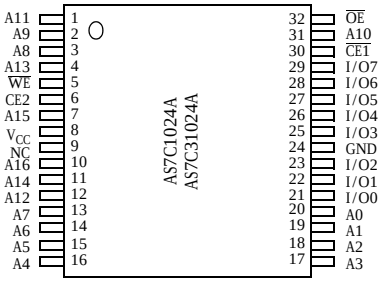


Pin arrangement

32-pin SOJ (300 mil)
32-pin SOJ (400 mil)



32-pin (8 x 20mm) TSOP I
32-pin (8 x 13.4mm) sTSOP1



Selection guide

		-10	-12	-15	-20	Unit
Maximum address access time		10	12	15	20	ns
Maximum output enable access time		5	6	7	8	ns
Maximum operating current	AS7C1024A	155	150	145	140	mA
	AS7C31024A	145	140	135	130	mA
Maximum CMOS standby current	AS7C1024A	10	10	10	10	mA
	AS7C31024A	5	5	5	5	mA

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Functional description

The AS7C1024A and AS7C31024A are high performance CMOS 1,048,576-bit Static Random Access Memory (SRAM) devices organized as 131,072 words x 8 bits. It is designed for memory applications where fast data access, low power, and simple interfacing are desired.

Equal address access and cycle times (t_{AA}, t_{RC}, t_{WC}) of 10/12/15/20 ns with output enable access times (t_{OE}) of 5, 6, 7, 8 ns are ideal for high performance applications. Active high and low chip enables ($\overline{CE1}$, CE2) permit easy memory expansion with multiple-bank systems.

When $\overline{CE1}$ is high or CE2 is low the devices enter standby mode. If inputs are still toggling, the device will consume I_{SB} power. If the bus is static, then full standby power is reached (I_{SB1}). For example, the AS7C31024A is guaranteed not to exceed 36mW under nominal full standby conditions. All devices in this family will retain data when VCC is reduced as low as 2.0V.

A write cycle is accomplished by asserting write enable ($\overline{WE}$) and both chip enables ($\overline{CE1}$, CE2). Data on the input pins I/O0-I/O7 is written on the rising edge of $\overline{WE}$ (write cycle 1) or the active-to-inactive edge of $\overline{CE1}$ or CE2 (write cycle 2). To avoid bus contention, external devices should drive I/O pins only after outputs have been disabled with output enable ($\overline{OE}$) or write enable ($\overline{WE}$).

A read cycle is accomplished by asserting output enable ($\overline{OE}$) and both chip enables ($\overline{CE1}$, CE2), with write enable ($\overline{WE}$) high. The chips drive I/O pins with the data word referenced by the input address. When either chip enable is inactive, output enable is inactive, or write enable is active, output drivers stay in high-impedance mode.

Absolute maximum ratings

Parameter		Symbol	Min	Max	Unit
Voltage on V_{CC} relative to GND	AS7C1024A	V_{t1}	–0.50	+7.0	V
	AS7C31024A	V_{t1}	-0.50	+5.0	V
Voltage on any pin relative to GND	Both	V_{t2}	–0.50	V_{CC} +0.50	V
Power dissipation	Both	P_D	–	1.0	W
Storage temperature (plastic)	Both	T_{stg}	–65	+150	°C
Ambient temperature with V_{CC} applied	Both	T_{bias}	–55	+125	°C
DC current into outputs (low)	Both	I_{OUT}	–	20	mA

Note: Stresses greater than those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Truth table

$\overline{CE1}$	CE2	$\overline{WE}$	$\overline{OE}$	Data	Mode
H	X	X	X	High Z	Standby (I_{SB}, I_{SB1})
X	L	X	X	High Z	Standby (I_{SB}, I_{SB1})
L	H	H	H	High Z	Output disable (I_{CC})
L	H	H	L	D_{OUT}	Read (I_{CC})
L	H	L	X	D_{IN}	Write ($_{ICC}$)

Key: X = Don't Care, L = Low, H = High

Recommended operating conditions

Parameter	Device	Symbol	Min	Nominal	Max	Unit
Supply voltage	AS7C1024A	V_{CC}	4.5	5.0	5.5	V
	AS7C31024A	V_{CC}	3.0	3.3	3.6	V
Input voltage	ASAS7C1024A	V_{IH}	2.2	–	V_{CC} + 0.5	V
	AS7C31024A	V_{IH}	2.0	–	V_{CC} + 0.5	V
		V_{IL} [1]	–0.5	–	0.8	V
Ambient operating temperature	commercial	T_A	0	–	70	°C
	industrial	T_A	–40	–	85	°C

1 V_{IL}min. = –3.0V for pulse width less than $t_{RC/2}$.

DC operating characteristics (over the operating range)[1]

Parameter	Sym	Test conditions	Device	-10		-12		-15		-20		Unit
				Min	Max	Min	Max	Min	Max	Min	Max	
Input leakage current	$\|I_{LI}\|$	V_{CC} = Max, V_{IN} = GND to V_{CC}	Both	–	1	–	1	–	1	–	1	µA
Output leakage current	$\|I_{LO}\|$	V_{CC} = Max, $\overline{CE1}$ = V_{IH} or CE2 = V_{IL}, V_{OUT} = GND to V_{CC}	Both	–	1	–	1	–	1	–	1	µA
Operating power supply current	I_{CC}	V_{CC} = Max, $\overline{CE1}$ = V_{IL}, CE2 = V_{IH}, f = f_{Max}, I_{OUT} = 0 mA	AS7C1024A	–	155	–	150	–	145	–	140	mA
			AS7C31024A	–	145	–	140	–	135	–	130	
Standby power supply current	I_{SB}	V_{CC} = Max, $\overline{CE1}$ ≥ V_{IH} and/or CE2 ≤ V_{IL}, V_{IN} = V_{IH} or V_{IL}, f = f_{Max}, I_{OUT} = 0mA	AS7C1024A	–	30	–	25	–	20	–	20	mA
			AS7C31024A	–	30	–	25	–	20	–	20	
	I_{SB1}	V_{CC} = Max, $\overline{CE1}$ ≥ V_{CC}–0.2V V_{IN} ≤ GND + 0.2V or V_{IN} ≥ V_{CC} –0.2V, f = 0	AS7C1024A	–	10	–	10	–	10	–	10	mA
			AS7C31024A	–	5	–	5	–	5	–	5	
Output voltage	V_{OL}	I_{OL} = 8 mA, V_{CC} = Min	Both	–	0.4	–	0.4	–	0.4	–	0.4	V
	V_{OH}	I_{OH} = –4 mA, V_{CC} = Min		2.4	–	2.4	–	2.4	–	2.4	–	V

Capacitance (f = 1 MHz, T_a = 25 °C, V_{CC} = NOMINAL)[2]

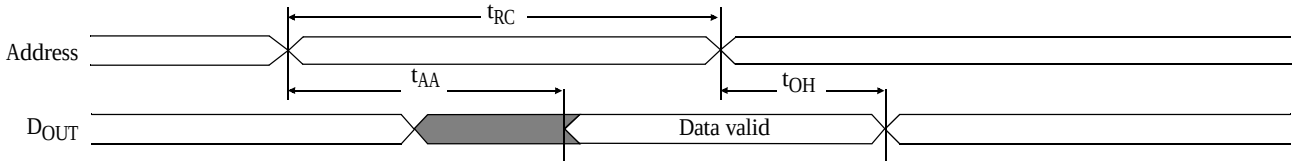
Parameter	Symbol	Signals	Test conditions	Max	Unit
Input capacitance	C_{IN}	A, $\overline{CE1}$, CE2, $\overline{WE}$, $\overline{OE}$	V_{IN} = 0V	5	pF
I/O capacitance	$C_{I/O}$	I/O	V_{IN} = V_{OUT} = 0V	7	pF

Read cycle (over the operating range)[3,9,12]

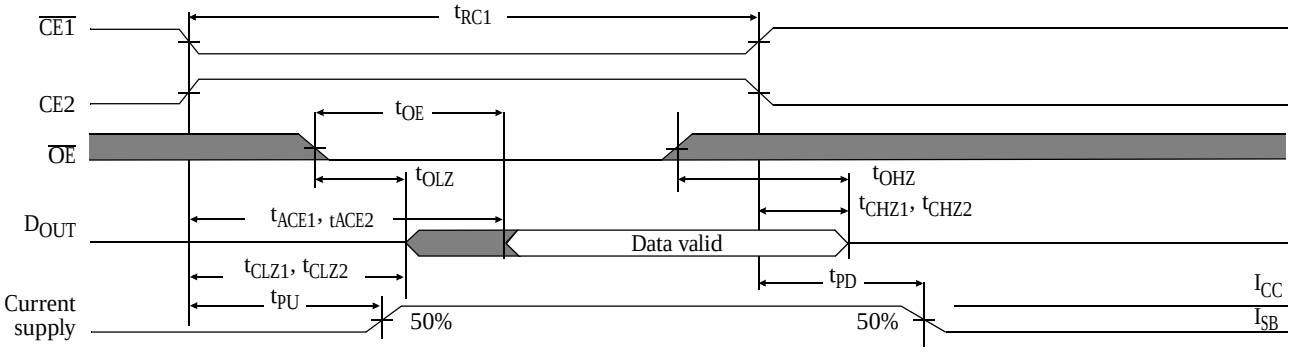
Parameter	Symbol	-10		-12		-15		-20		Unit	Notes
		Min	Max	Min	Max	Min	Max	Min	Max		
Read cycle time	t_{RC}	10	–	12	–	15	–	20	–	ns	
Address access time	t_{AA}	–	10	–	12	–	15	–	20	ns	3
Chip enable ($\overline{CE1}$) access time	t_{ACE1}	–	10	–	12	–	15	–	20	ns	3, 12
Chip enable (CE2) access time	t_{ACE2}	–	10	–	12	–	15	–	20	ns	3, 12
Output enable ($\overline{OE}$) access time	t_{OE}	–	5	–	6	–	7	–	8	ns	
Output hold from address change	t_{OH}	2	–	3	–	3	–	3	–	ns	5
$\overline{CE1}$ Low to output in low Z	t_{CLZ1}	0	–	0	–	0	–	0	–	ns	4, 5, 12
CE2 High to output in low Z	t_{CLZ2}	0	–	0	–	0	–	0	–	ns	4, 5, 12
$\overline{CE1}$ Low to output in high Z	t_{CHZ1}	–	3	–	3	–	4	–	5	ns	4, 5, 12
CE2 Low to output in high Z	t_{CHZ2}	–	3	–	3	–	4	–	5	ns	4, 5, 12
$\overline{OE}$ Low to output in low Z	t_{OLZ}	0	–	0	–	0	–	0	–	ns	4, 5
$\overline{OE}$ High to output in high Z	t_{OHZ}	–	3	–	3	–	4	–	5	ns	4, 5
Power up time	t_{PU}	0	–	0	–	0	–	0	–	ns	4, 5, 12
Power down time	t_{PD}	–	10	–	12	–	15	–	20	ns	4, 5, 12

Key to switching waveforms

Read waveform 1 (address controlled)[3,6,7,9,12]



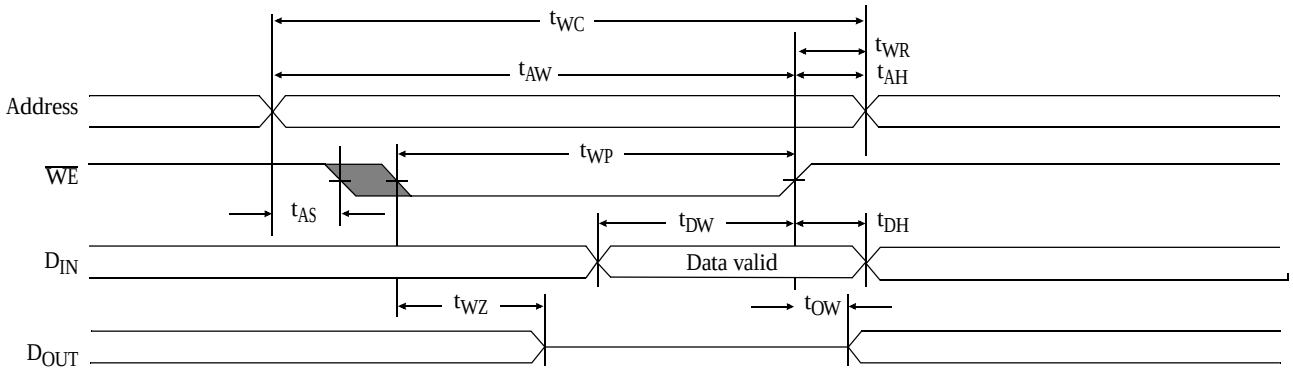
Read waveform 2 ($\overline{CE1}$, CE2, and $\overline{OE}$ controlled)[3,6,8,9,12]



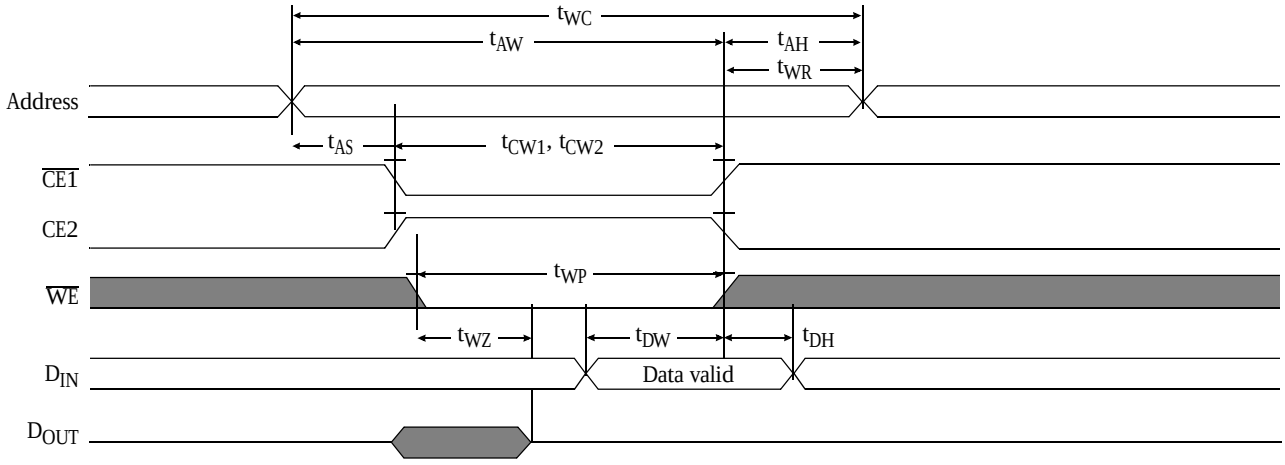
Write cycle (over the operating range)[11, 12]

Parameter	Symbol	-10		-12		-15		-20		Unit	Notes
		Min	Max	Min	Max	Min	Max	Min	Max		
Write cycle time	t_{WC}	10	–	12	–	15	–	20	–	ns	
Chip enable ($\overline{CE1}$) to write end	t_{CW1}	8	–	10	–	12	–	12	–	ns	12
Chip enable (CE2) to write end	t_{CW2}	8	–	10	–	12	–	12	–	ns	12
Address setup to write end	t_{AW}	8	–	9	–	10	–	12	–	ns	
Address setup time	t_{AS}	0	–	0	–	0	–	0	–	ns	12
Write pulse width	t_{WP}	7	–	8	–	9	–	12	–	ns	
Write recovery time	t_{WR}	0	–	0	–	0	–	0	–	ns	
Address hold from end of write	t_{AH}	0	–	0	–	0	–	0	–	ns	
Data valid to write end	t_{DW}	5	–	6	–	8	–	10	–	ns	
Data hold time	t_{DH}	0	–	0	–	0	–	0	–	ns	4, 5
Write enable to output in high Z	t_{WZ}	–	6	–	6	–	6	–	8	ns	4, 5
Output active from write end	t_{OW}	1	–	1	–	1	–	2	–	ns	4, 5

Write waveform 1 ($\overline{WE}$ controlled)[10,11,12]



Write waveform 2 ($\overline{CE1}$ and CE2 controlled)[10,11,12]



AC test conditions

- Output load: see Figure B or Figure C.
- Input pulse level: GND to 3.0V. See Figure A.
- Input rise and fall times: 2 ns. See Figure A.
- Input and output timing reference levels: 1.5V.

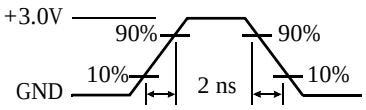


Figure A: Input pulse

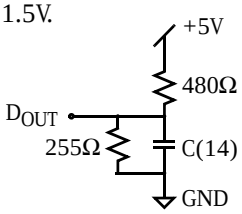


Figure B: 5V Output load

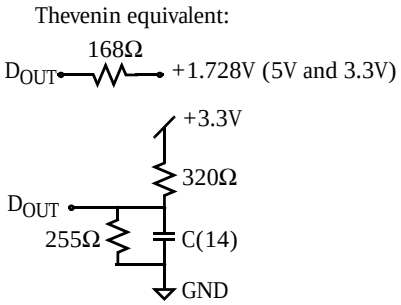


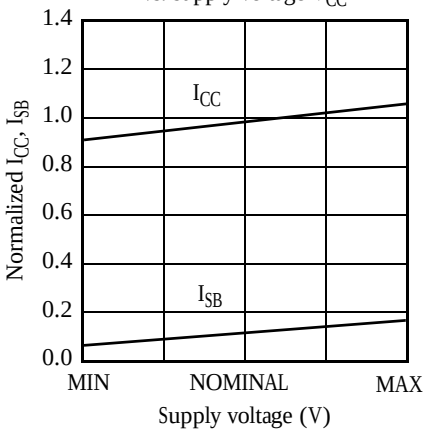
Figure C: 3.3V Output load

Notes

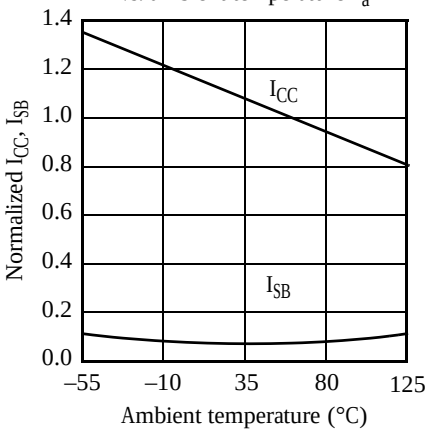
1 During V_{CC} power-up, a pull-up resistor to V_{CC} on $\overline{CE1}$ is required to meet I_{SB} specification.
2 This parameter is sampled and not 100% tested.
3 For test conditions, see *AC Test Conditions*, Figures A, B, and C.
4 t_{CLZ} and t_{CHZ} are specified with CL = 5pF, as in Figure C. Transition is measured ±500mV from steady-state voltage.
5 This parameter is guaranteed, but not 100% tested.
6 $\overline{WE}$ is High for read cycle.
7 $\overline{CE1}$ and $\overline{OE}$ are Low and CE2 is High for read cycle.
8 Address valid prior to or coincident with $\overline{CE1}$ transition Low.
9 All read cycle timings are referenced from the last valid address to the first transitioning address.
10 $\overline{CE1}$ or $\overline{WE}$ must be High or CE2 Low during address transitions. Either $\overline{CE1}$ or $\overline{WE}$ asserting high terminates a write cycle.
11 All write cycle timings are referenced from the last valid address to the first transitioning address.
12 $\overline{CE1}$ and CE2 have identical timing.
13 C=30pF, except all high Z and low Z parameters, C=5pF.
14 2V data retention applies to commercial temperature operating range only.

Typical DC and AC Characteristcs

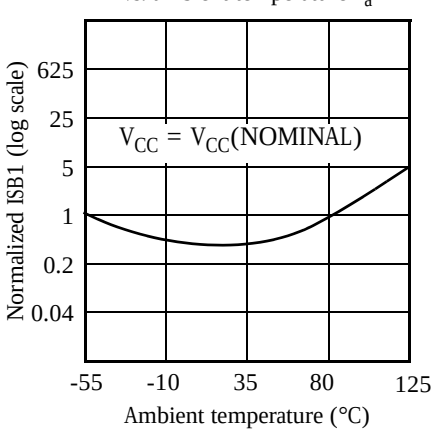
Normalized supply current I_{CC}, I_{SB} vs. supply voltage V_{CC}



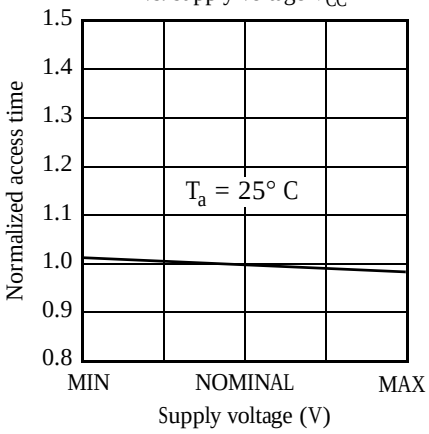
Normalized supply current I_{CC}, I_{SB} vs. ambient temperature T_a



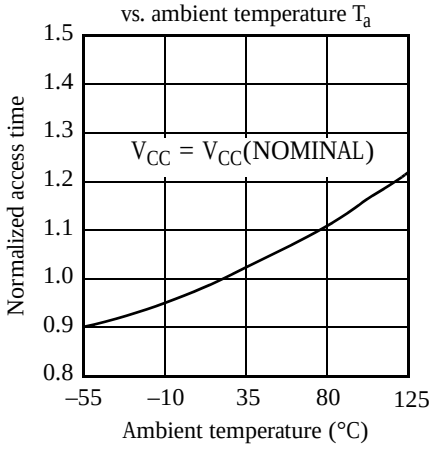
Normalized supply current I_{SB1} vs. ambient temperature T_a



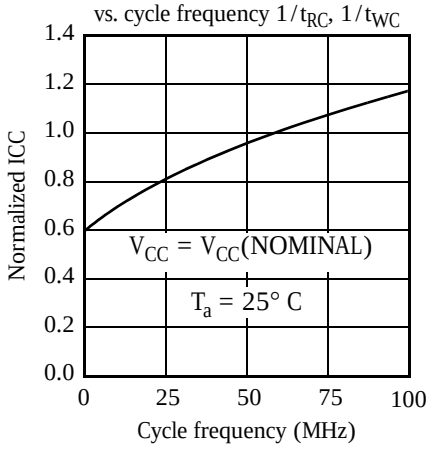
Normalized access time t_{AA} vs. supply voltage V_{CC}



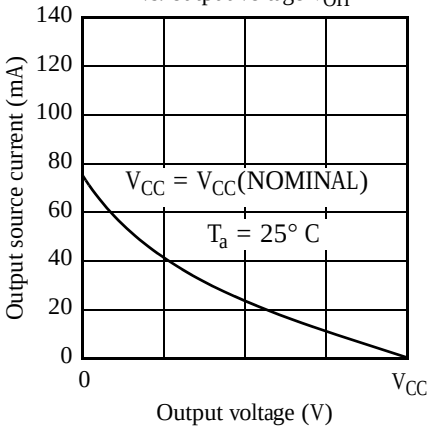
Normalized access time t_{AA} vs. ambient temperature T_a



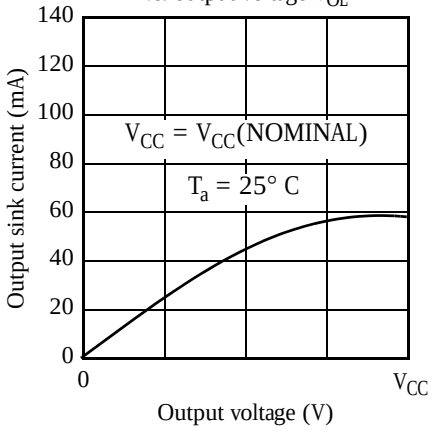
Normalized supply current I_{CC} vs. cycle frequency $1/t_{RC}$, $1/t_{WC}$



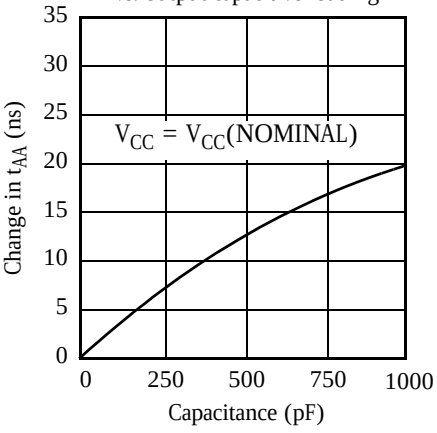
Output source current I_{OH} vs. output voltage V_{OH}



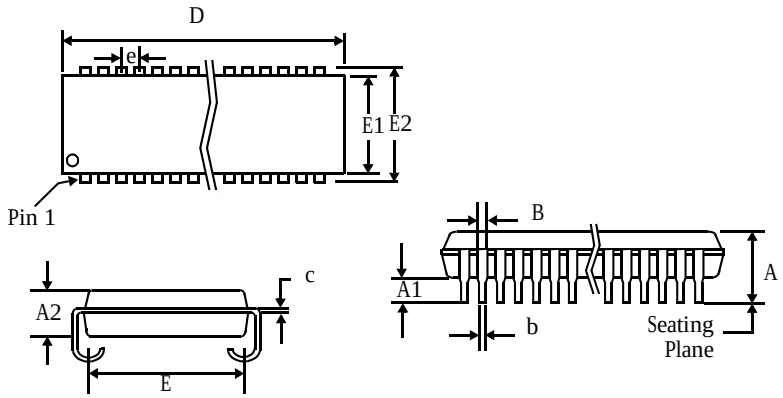
Output sink current I_{OL} vs. output voltage V_{OL}



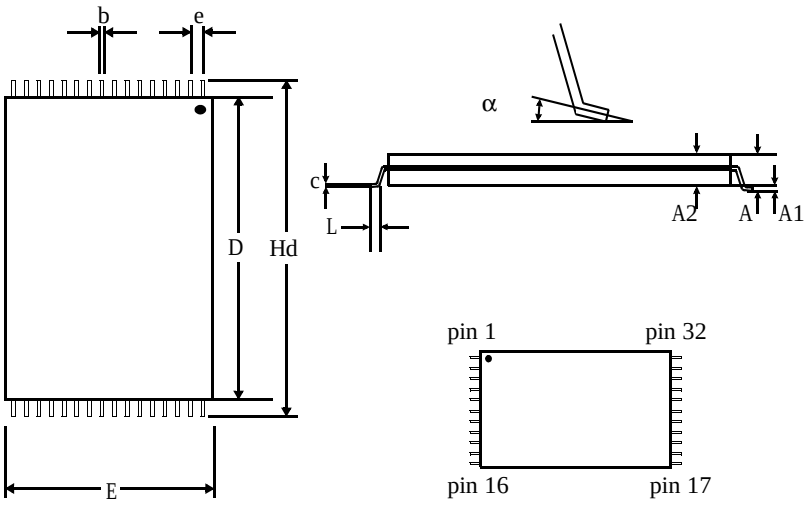
Typical access time change Δt_{AA} vs. output capacitive loading



Package dimensions



	32-pin SOJ 300 mil		32-pin SOJ 400 mil	
	Min	Max	Min	Max
A	-	0.145	-	0.145
A1	0.025	-	0.025	-
A2	0.086	0.105	0.086	0.115
B	0.026	0.032	0.026	0.032
b	0.014	0.020	0.015	0.020
c	0.006	0.013	0.007	0.013
D	0.820	0.830	0.820	0.830
E	0.250	0.275	0.360	0.380
E1	0.292	0.305	0.395	0.405
E2	0.330	0.340	0.435	0.445
e	0.050 BSC		0.050 BSC	



	32-pin TSOP 8×20 mm	
	Min	Max
A	–	1.20
A1	0.05	0.15
A2	0.95	1.05
b	0.17	0.27
c	0.10	0.21
D	18.20	18.60
e	0.50 nominal	
E	7.80	8.20
Hd	19.80	20.20
L	0.50	0.70
α	0°	5°

Ordering codes

Package \ Access time	Volt/Temp	10 ns	12 ns	15 ns	20 ns
Plastic SOJ, 300 mil	5V commercial	AS7C1024A-10TJC	AS7C1024A-12TJC	AS7C1024A-15TJC	AS7C1024A-20TJC
	5V industrial	AS7C1024A-10TJI	AS7C1024A-12TJI	AS7C1024A-15TJI	AS7C1024A-20TJI
	3.3V commercial	AS7C31024A-10TJC	AS7C31024A-12TJC	AS7C31024A-15TJC	AS7C31024A-20TJC
	3.3V industrial	AS7C31024A-10TJI	AS7C31024A-12TJI	AS7C31024A-15TJI	AS7C31024A-20TJI
Plastic SOJ, 400 mil	5V commercial	AS7C1024A-10JC	AS7C1024A-12JC	AS7C1024A-15JC	AS7C1024A-20JC
	5V industrial	AS7C1024A-10JI	AS7C1024A-12JI	AS7C1024A-15JI	AS7C1024A-20JI
	3.3V commercial	AS7C31024A-10JC	AS7C31024A-12JC	AS7C31024A-15JC	AS7C31024A-20JC
	3.3V industrial	AS7C31024A-10JI	AS7C31024A-12JI	AS7C31024A-15JI	AS7C31024A-20JI
TSOP1 8×20 mm	5V commercial	AS7C1024A-10TC	AS7C1024A-12TC	AS7C1024A-15TC	AS7C1024A-20TC
	5V industrial	AS7C1024A-10TI	AS7C1024A-12TI	AS7C1024A-15TI	AS7C1024A-20TI
	3.3V commercial	AS7C31024A-10TC	AS7C31024A-12TC	AS7C31024A-15TC	AS7C31024A-20TC
	3.3V industrial	AS7C31024A-10TI	AS7C31024A-12TI	AS7C31024A-15TI	AS7C31024A-20TI
sTSOP1 8 x 13.4mm	5V commercial	AS7C1024A-10STC	AS7C1024A-12STC	AS7C1024A-15STC	AS7C1024A-20STC
	5V industrial	AS7C1024A-10STI	AS7C1024A-12STI	AS7C1024A-15STI	AS7C1024A-20STI
	3.3V commercial	AS7C31024A-10STC	AS7C31024A-12STC	AS7C31024A-15STC	AS7C31024A-20STC
	3.3V industrial	AS7C31024A-10STI	AS7C31024A-12STI	AS7C31024A-15STI	AS7C31024A-20STI

Part numbering system

AS7C	X	1024A	–XX	X	X
SRAM prefix	Blank=5V CMOS 3=3.3V CMOS	Device number	Access time	Package:T=TSOP1 8×20 mm ST=sTSOP1 8 x 13.4 mm J=SOJ 400 mil TJ=SOJ 300 mil	Temperature range C = Commercial, 0°C to 70°C I = Industrial, -40°C to 85°C

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